

NPN SILICON RF TRANSISTOR 2SC5015

NPN EPITAXIAL SILICON RF TRANSISTOR FOR HIGH-FREQUENCY LOW-NOISE AMPLIFICATION 4-PIN SUPER MINIMOLD (18)

FEATURES

- High fr: fr = 12 GHz TYP. @ VcE = 3 V, Ic = 10 mA, f = 2 GHz
- · Low noise and high gain
- · Low voltage operation
- · 4-pin super minimold (18) package

★ ORDERING INFORMATION

Part Number	Quantity	Supplying Form	
2SC5015	50 pcs (Non reel)	• 8 mm wide embossed taping	
2SC5015-T1	3 kpcs/reel	Pin 3 (Base), Pin 4 (Emitter) face the perforation side of the tape	

Remark To order evaluation samples, contact your nearby sales office.

The unit sample quantity is 50 pcs.

ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vсво	9	V
Collector to Emitter Voltage	VCEO	6	٧
Emitter to Base Voltage	V _{ЕВО}	2	٧
Collector Current	lc	30	mA
Total Power Dissipation	Ptot	150	mW
Junction Temperature	Tj	150	ç
Storage Temperature	T _{stg}	-65 to +150	°C

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.

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The mark ★ shows major revised points.

Printed in Japan

ELECTRICAL CHARACTERISTICS (TA = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit		
DC Characteristics								
Collector Cut-off Current	Ісво	VcB = 5 V, IE = 0 mA	-	-	0.1	μΑ		
Emitter Cut-off Current	ІЕВО	V _{EB} = 1 V, I _C = 0 mA	-	-	0.1	μΑ		
DC Current Gain	hfe Note 1	Vce = 3 V, Ic = 10 mA	75	-	150	-		
RF Characteristics								
Gain Bandwidth Product	f⊤	Vce = 3 V, Ic = 10 mA, f = 2 GHz	-	12	_	GHz		
Insertion Power Gain	S _{21e} ²	Vce = 3 V, Ic = 10 mA, f = 2 GHz	9	11	_	dB		
Noise Figure	NF	Vce = 3 V, Ic = 3 mA, f = 2 GHz	_	1.5	2.5	dB		
Reverse Transfer Capacitance	Cre Note 2	Vсв = 3 V, IE = 0 mA, f = 1 MHz	-	0.3	0.5	pF		

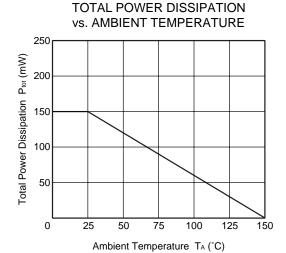
Notes 1. Pulse measurement: PW \leq 350 μ s, Duty Cycle \leq 2%

2. Collector to base capacitance when the emitter grounded

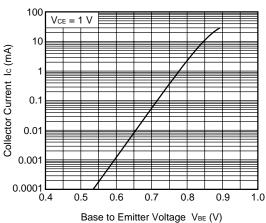
hfe CLASSIFICATION

Rank	KB		
Marking	T83		
h _{FE} Value	75 to 150		

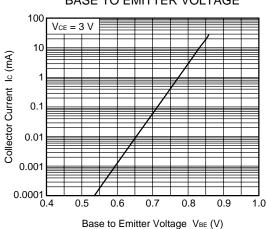
★ TYPICAL CHARACTERISTICS (T_A = +25°C, unless otherwise specified)



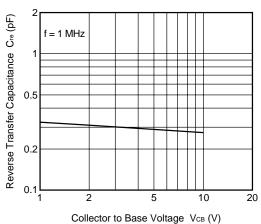
COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



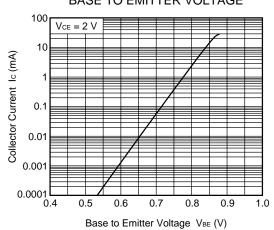
COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



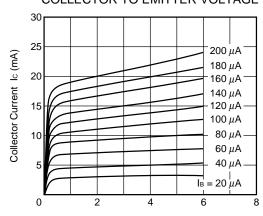
REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



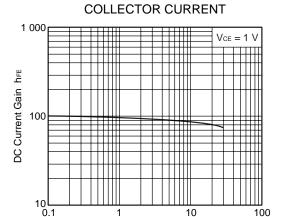
COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



COLLECTOR CURRENT vs.
COLLECTOR TO EMITTER VOLTAGE



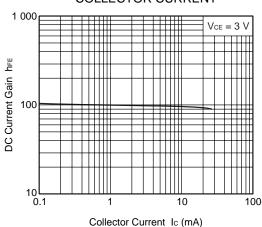
Collector to Emitter Voltage VcE (V)



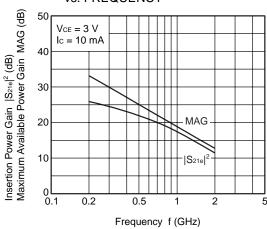
DC CURRENT GAIN vs.

DC CURRENT GAIN vs. COLLECTOR CURRENT

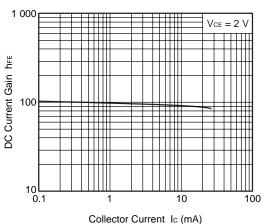
Collector Current Ic (mA)



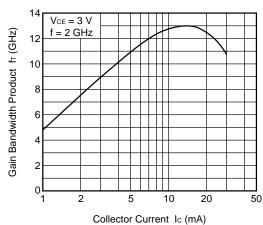
INSERTION POWER GAIN, MAG vs. FREQUENCY



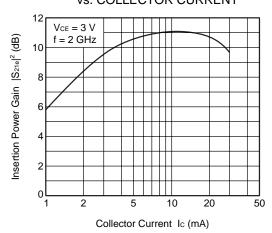
DC CURRENT GAIN vs. COLLECTOR CURRENT



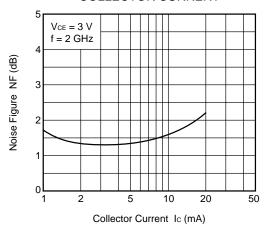
GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT



INSERTION POWER GAIN vs. COLLECTOR CURRENT



NOISE FIGURE vs. COLLECTOR CURRENT



Remark The graphs indicate nominal characteristics.

S-PARAMETERS

S-parameters/Noise parameters are provided on the NEC Compound Semiconductor Devices Web site in a form (S2P) that enables direct import to a microwave circuit simulator without keyboard input.

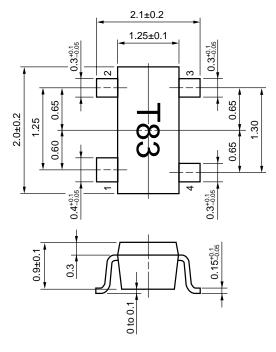
Click here to download S-parameters.

 $[\mathsf{RF} \ \mathsf{and} \ \mathsf{Microwave}] \to [\mathsf{Device} \ \mathsf{Parameters}]$

URL http://www.csd-nec.com/

PACKAGE DIMENSIONS

4-PIN SUPER MINIMOLD (18) (UNIT: mm)



PIN CONNECTIONS

- 1. Collector
- 2. Emitter
- 3. Base
- 4. Emitter

NEC 2SC5015

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▶ For further information, please contact

${\bf NEC\ Compound\ Semiconductor\ Devices, Ltd.}$

5th Sales Group, Sales Division TEL: +81-44-435-1588 FAX: +81-44-435-1579 E-mail: salesinfo@csd-nec.com

NEC Compound Semiconductor Devices Hong Kong Limited

Hong Kong Head Office TEL: +852-3107-7303 FAX: +852-3107-7309 E-mail: ncsd-hk@elhk.nec.com.hk

Taipei Branch Office TEL: +886-2-8712-0478 FAX: +886-2-2545-3859 Korea Branch Office TEL: +82-2-558-2120 FAX: +82-2-558-5209

NEC Electronics (Europe) GmbH http://www.ee.nec.de/

TEL: +49-211-6503-01 FAX: +49-211-6503-487

California Eastern Laboratories, Inc. http://www.cel.com/

TEL: +1-408-988-3500 FAX: +1-408-988-0279

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